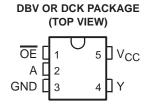
## SN74LVC1G125 SINGLE BUS BUFFER GATE WITH 3-STATE OUTPUTS

SCES223C - APRIL 1999 - REVISED FEBRUARY 2000

- EPIC<sup>™</sup> (Enhanced-Performance Implanted CMOS) Submicron Process
- I<sub>off</sub> Feature Supports Partial-Power-Down Mode Operation
- Supports 5-V V<sub>CC</sub> Operation
- Package Options Include Plastic Small-Outline Transistor (DBV, DCK) Packages



### description

This bus buffer gate is designed for 1.65-V to 5.5-V  $V_{CC}$  operation.

The SN74LVC1G125 features a single line driver with a 3-state output. The output is disabled when the output-enable  $(\overline{OE})$  input is high.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

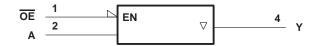
This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The SN74LVC1G125 is characterized for operation from -40°C to 85°C.

### **FUNCTION TABLE**

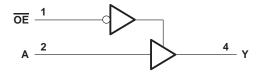
INPU	JTS	OUTPUT			
OE	Α	Y			
L	Н	Н			
L L		L			
Н	Χ	Z			

### logic symbol†



<sup>&</sup>lt;sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

### logic diagram (positive logic)





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## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage range, V <sub>CC</sub>	–0.5 V to 6.5 V
Input voltage range, V <sub>I</sub> (see Note 1)	
Output voltage range, VO (see Notes 1 and 2)	$\dots$ -0.5 V to V <sub>CC</sub> + 0.5 V
Input clamp current, $I_{ K }(V_{ I } < 0)$	
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0)	–50 mA
Continuous output current, IO	±50 mA
Continuous current through V <sub>CC</sub> or GND	±100 mA
Package thermal impedance, $\theta_{JA}$ (see Note 3): DBV package	347°C/W
DCK package	389°C/W
Storage temperature range, T <sub>stq</sub>	–65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.
  - 2. The value of V<sub>CC</sub> is provided in the recommended operating conditions table.
  - 3. The package thermal impedance is calculated in accordance with JESD 51.

## recommended operating conditions (see Note 4)

			MIN	MAX	UNIT	
\/	Cumply voltage	Operating	1.65	5.5	V	
<sub>V</sub> CC	Supply voltage Data retention only		1.5		V	
		V <sub>CC</sub> = 1.65 V to 1.95 V	0.65 × V <sub>CC</sub>			
\/	High-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7		V	
VIH		$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$	2		V	
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	0.7 × V <sub>CC</sub>			
		V <sub>CC</sub> = 1.65 V to 1.95 V		0.35 × V <sub>CC</sub>		
.,	Low lovel input valtage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	<sub>v</sub>	
VIL	Low-level input voltage	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$		0.8	V	
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		$0.3 \times V_{CC}$		
٧ <sub>I</sub>	Input voltage		0	5.5	V	
٧o	Output voltage		0	Vcc	V	
		V <sub>CC</sub> = 1.65 V		-4		
		V <sub>CC</sub> = 2.3 V		-8		
IOH	High-level output current	VCC = 3 V		-16	mA	
		vCC = 2 v		-24		
		V <sub>CC</sub> = 4.5 V		-32		
		V <sub>CC</sub> = 1.65 V		4		
		V <sub>CC</sub> = 2.3 V		8		
l <sub>OL</sub>	Low-level output current	V 3 V		16	mA	
	V <sub>CC</sub> = 3 V			24		
	V <sub>CC</sub> = 4.5 V	V <sub>CC</sub> = 4.5 V		32		
		$V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}, 2.5 \text{ V} \pm 0.2 \text{ V}$		20		
$\Delta t/\Delta v$	Input transition rise or fall rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		10	ns/V	
		$V_{CC} = 5 V \pm 0.5 V$		5		
TA	Operating free-air temperature		-40	85	°C	

NOTE 4: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



# PRODUCT PREVIEW

## electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARA	AMETER	TEST CONDITIONS	VCC	MIN	TYP <sup>†</sup>	MAX	UNIT	
		$I_{OH} = -100 \mu A$	1.65 V to 5.5 V	V <sub>CC</sub> -0.1				
		$I_{OH} = -4 \text{ mA}$	1.65 V	1.2				
l .,		$I_{OH} = -8 \text{ mA}$	2.3 V	1.9			.,	
VOH		$I_{OH} = -16 \text{ mA}$	2.1/	2.4			V	
		I <sub>OH</sub> = -24 mA	3 V	2.3				
		$I_{OH} = -32 \text{ mA}$	4.5 V	3.8				
		I <sub>OL</sub> = 100 μA	1.65 V to 5.5 V			0.1		
		I <sub>OL</sub> = 4 mA	1.65 V			0.45		
l .,		I <sub>OL</sub> = 8 mA	2.3 V			0.3		
VOL		I <sub>OL</sub> = 16 mA	2.1/			0.4	V	
		I <sub>OL</sub> = 24 mA	3 V			0.55		
		I <sub>OL</sub> = 32 mA	4.5 V			0.55		
	A or OE inputs	V <sub>I</sub> = 5.5 V or GND	0 to 5.5 V			±5	μΑ	
l <sub>off</sub>		$V_I$ or $V_O = 5.5 V$	0			±10	μА	
loz		V <sub>O</sub> = 0 to 5.5 V	3.6 V			10	μА	
ICC		$V_I = 5.5 \text{ V or GND}, \qquad I_O = 0$	1.65 V to 5.5 V			10	μΑ	
Δlcc		One input at V <sub>CC</sub> – 0.6 V, Other inputs at V <sub>CC</sub> or GND	3 V to 5.5 V			500	μΑ	
Ci		VI = VCC or GND	3.3 V				pF	

<sup>&</sup>lt;sup>†</sup> All typical values are at  $V_{CC} = 3.3 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

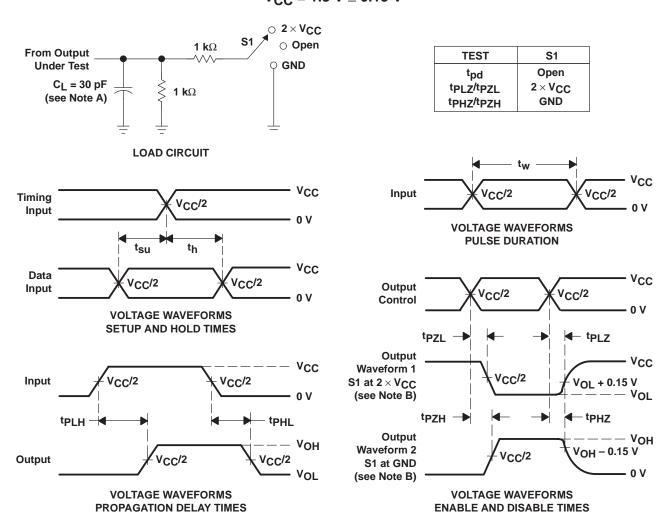
## switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figures 1 through 4)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> =		VCC =		V <sub>CC</sub> =		VCC =	= 5 V 5 V	UNIT	
	(INFOT)	(001701)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX		
<sup>t</sup> pd	А	Υ									ns	
t <sub>en</sub>	ŌĒ	Υ									ns	
<sup>t</sup> dis	ŌĒ	Y									ns	

## operating characteristics, $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	V <sub>CC</sub> = 1.8 V	V <sub>CC</sub> = 2.5 V	V <sub>CC</sub> = 3.3 V	V <sub>CC</sub> = 5 V	UNIT
TANAMETER		TYP		TYP	TYP	TYP	0
C <sub>pd</sub>	Power dissipation capacitance	f = 10 MHz					pF

## PARAMETER MEASUREMENT INFORMATION $V_{CC} = 1.8 V \pm 0.15 V$

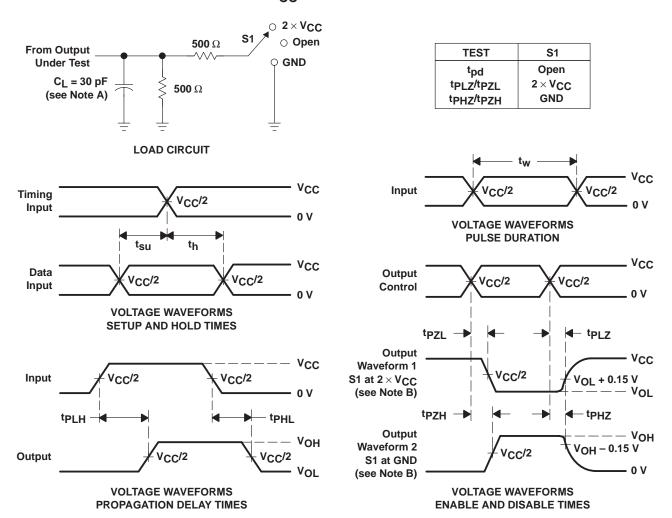


- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ ,  $t_f \leq$  2 ns,  $t_f \leq$  2 ns.
  - D. The outputs are measured one at a time with one transition per measurement.
  - E. tpLz and tpHz are the same as tdis.
  - F. tpzL and tpzH are the same as ten.
  - G. tpl H and tpHI are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms



## PARAMETER MEASUREMENT INFORMATION $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$

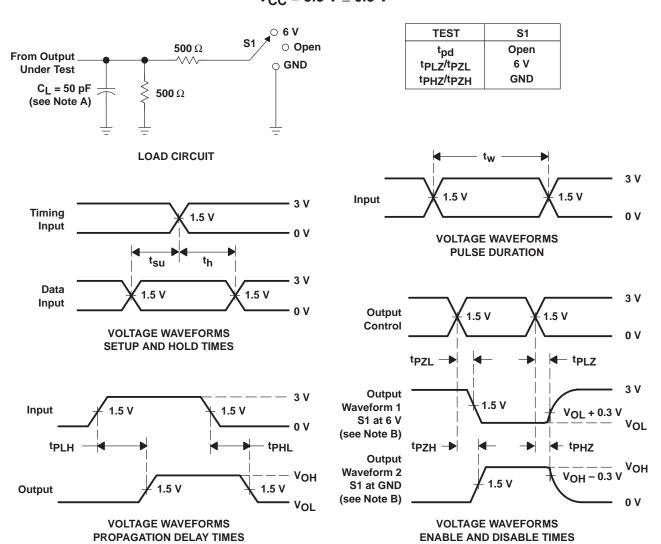


NOTES: A.  $C_L$  includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50~\Omega$ ,  $t_f \leq$  2 ns,  $t_f \leq$  2 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLz and tpHz are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tplH and tpHL are the same as tpd.

Figure 2. Load Circuit and Voltage Waveforms

## PARAMETER MEASUREMENT INFORMATION $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$



- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_Q = 50 \Omega$ ,  $t_f \leq 2.5 \text{ ns.}$
  - D. The outputs are measured one at a time with one transition per measurement.
  - E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - F. tpzL and tpzH are the same as ten.
  - G. tplH and tpHL are the same as tpd.

Figure 3. Load Circuit and Voltage Waveforms



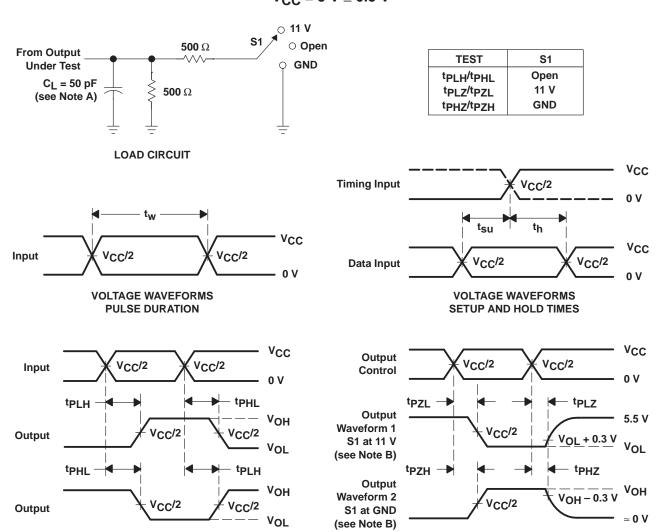
**VOLTAGE WAVEFORMS** 

**ENABLE AND DISABLE TIMES** 

LOW- AND HIGH-LEVEL ENABLING

## PRODUCT PREVIEW

## PARAMETER MEASUREMENT INFORMATION $V_{CC}$ = 5 V $\pm$ 0.5 V



NOTES: A. C<sub>1</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_Q = 50 \Omega$ ,  $t_f \leq 2.5 \text{ ns.}$
- D. The outputs are measured one at a time with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .

**VOLTAGE WAVEFORMS** 

PROPAGATION DELAY TIMES

**INVERTING AND NONINVERTING OUTPUTS** 

- F. tpzL and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd.

Figure 4. Load Circuit and Voltage Waveforms



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